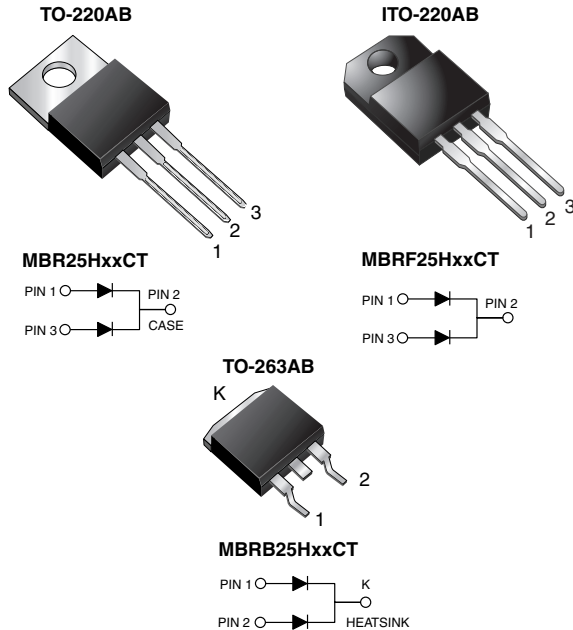


Dual Common Cathode Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance



FEATURES

- Power pack
- Guardring for overvoltage protection
- Lower power losses, high efficiency
- Low forward voltage drop
- Low leakage current
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- AEC-Q101 qualified available
 - Automotive ordering code: base P/NHE3_A
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT

TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, or polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade

Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified

Base P/NHE3_X - RoHS-compliant, AEC-Q101 qualified

("_X" denotes revision code, e.g. A, B, ...)

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 15 A
V_{RRM}	35 V to 60 V
I_{FSM}	150 A
V_F	0.54 V, 0.60 V
I_R	100 μ A
T_J max.	175 °C
Package	TO-220AB, ITO-220AB, TO-263AB
Diode variations	Common cathode

MAXIMUM RATINGS ($T_C = 25\text{ °C}$ unless otherwise noted)					
PARAMETER	SYMBOL	MBR25H35CT	MBR25H45CT	MBR25H60CT	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	35	45	60	V
Working peak reverse voltage	V_{RWM}	35	45	60	
Maximum DC blocking voltage	V_{DC}	35	45	60	
Max. average forward rectified current (fig. 1)	$I_{F(AV)}$	total device			A
		per diode			
Non-repetitive avalanche energy per diode at 25 °C, $I_{AS} = 4\text{ A}$, $L = 10\text{ mH}$	E_{AS}	80			mJ
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I_{FSM}	150			A
Peak repetitive reverse surge current per diode at $t_p = 2.0\text{ }\mu\text{s}$, 1 kHz	I_{RRM}	1.0	0.5		A
Peak non-repetitive reverse energy (8/20 μs waveform)	E_{RSM}	25	20		mJ
Electrostatic discharge capacitor voltage Human body model: $C = 100\text{ pF}$, $R = 1.5\text{ k}\Omega$	V_C	25			kV
Voltage rate of change (rated V_R)	dV/dt	10 000			V/ μs
Operating junction and storage temperature range	T_J, T_{STG}	-65 to +175			°C
Isolation voltage (ITO-220AB only) from terminal to heatsink $t = 1\text{ min}$	V_{AC}	1500			V



ELECTRICAL CHARACTERISTICS ($T_C = 25\text{ }^\circ\text{C}$ unless otherwise noted)								
PARAMETER	SYMBOL	TEST CONDITIONS		MBR25H35CT MBR25H45CT		MBR25H60CT		UNIT
				TYP.	MAX.	TYP.	MAX.	
Maximum instantaneous forward voltage per diode	V_F ⁽¹⁾	$I_F = 15\text{ A}$	$T_J = 25\text{ }^\circ\text{C}$	-	0.64	-	0.70	V
			$T_J = 125\text{ }^\circ\text{C}$	0.50	0.54	0.56	0.60	
		$I_F = 30\text{ A}$	$T_J = 25\text{ }^\circ\text{C}$	-	0.74	-	0.85	
			$T_J = 125\text{ }^\circ\text{C}$	0.63	0.67	0.68	0.72	
Maximum reverse current per diode	I_R ⁽²⁾	Rated V_R	$T_J = 25\text{ }^\circ\text{C}$	-	100	-	100	μA
			$T_J = 125\text{ }^\circ\text{C}$	6.0	20	4.0	20	mA

Notes⁽¹⁾ Pulse test: 300 μs pulse width, 1 % duty cycle⁽²⁾ Pulse test: pulse width $\leq 40\text{ ms}$

THERMAL CHARACTERISTICS ($T_C = 25\text{ }^\circ\text{C}$ unless otherwise noted)					
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT
Thermal resistance, junction to case per diode	$R_{\theta JC}$	1.5	4.5	1.5	$^\circ\text{C/W}$

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AB	MBR25H45CT-E3/45	1.85	45	50/tube	Tube
ITO-220AB	MBRF25H45CT-E3/45	1.99	45	50/tube	Tube
TO-263AB	MBRB25H45CT-E3/45	1.35	45	50/tube	Tube
TO-263AB	MBRB25H45CT-E3/81	1.35	81	800/reel	Tape and reel
TO-220AB	MBR25H60CT-E3/4W ⁽¹⁾	1.85	4W	50/tube	Tube
TO-220AB	MBR25H45CTHE3/45 ⁽¹⁾	1.85	45	50/tube	Tube
ITO-220AB	MBRF25H45CTHE3/45 ⁽¹⁾	1.99	45	50/tube	Tube
TO-263AB	MBRB25H45CTHE3/45 ⁽¹⁾	1.35	45	50/tube	Tube
TO-263AB	MBRB25H45CTHE3/81 ⁽¹⁾	1.35	81	800/reel	Tape and reel
TO-263AB	MBRB25H45CTHE3_A/P ⁽¹⁾	1.35	P	50/tube	Tube
TO-263AB	MBRB25H45CTHE3_A/I ⁽¹⁾	1.35	I	800/reel	Tape and reel

Note⁽¹⁾ AEC-Q101 qualified



RATINGS AND CHARACTERISTICS CURVES ($T_C = 25\text{ }^\circ\text{C}$ unless otherwise noted)

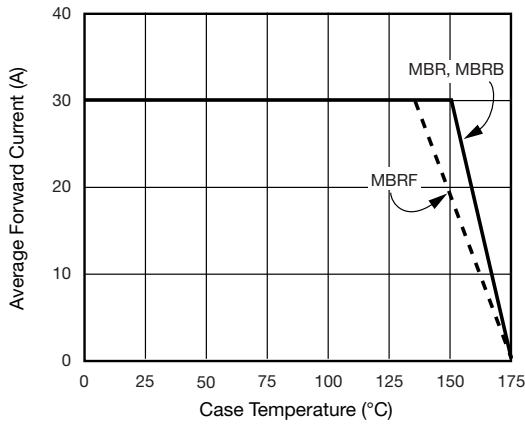


Fig. 1 - Forward Derating Curve (Total)

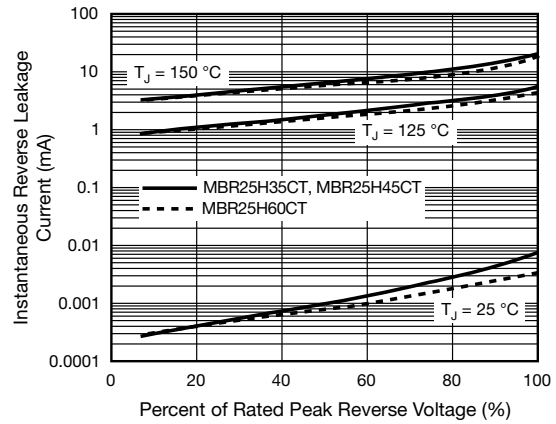


Fig. 4 - Typical Reverse Characteristics Per Diode

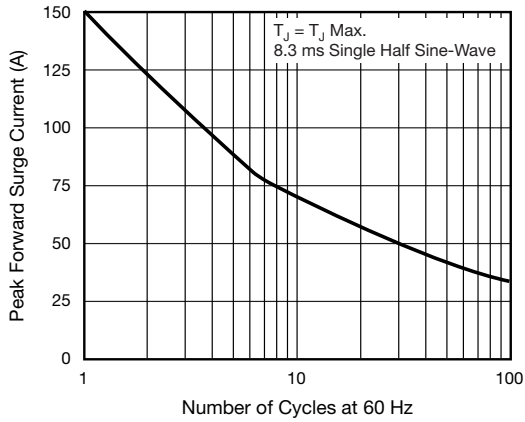


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

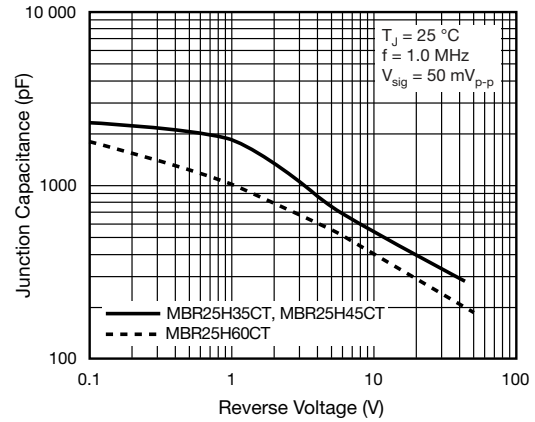


Fig. 5 - Typical Junction Capacitance Per Diode

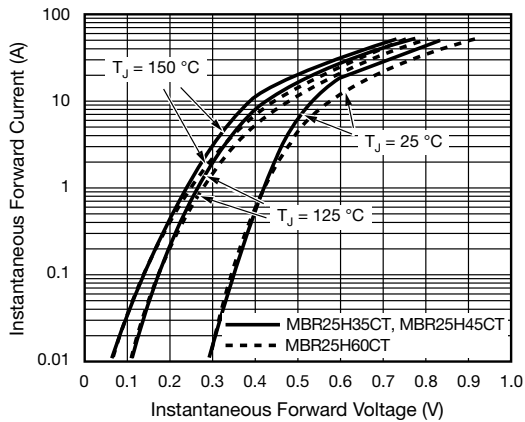


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

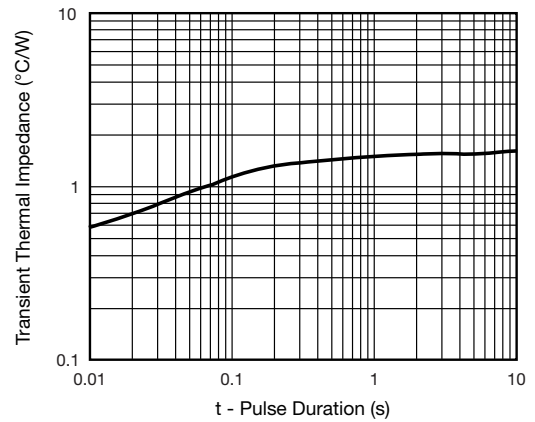


Fig. 6 - Typical Transient Thermal Impedance Per Diode



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